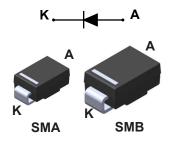


1 A - 400 V ultrafast recovery diode





DO-15

Features

- · Negligible switching losses
- Low forward voltage drop
- · High junction temperature
- ECOPACK compliant

Applications

- · Switching diode
- · Telecom power

Description

The STTH1R04 series uses ST's new 400 V planar Pt doping technology. The STTH1R04 is specially suited for switching mode base drive and transistor circuits.

Packaged in SMA, SMB and DO-15, the STTH1R04 is ideal for use low voltage, high frequency inverters, free wheeling and polarity protection

Product status
STTH1R04

Product summary				
Symbol	Value			
I _{F(AV)}	1 A			
V _{RRM}	400 V			
T _{j(max.)}	175 °C			
V _{F(typ.)}	0.9 V			
trr(typ.)	14 ns			



1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	pol Parameter				Unit
V _{RRM}	Repetitive peak reverse voltage			400	V
		SMA	T _L = 125 °C		
I _{F(AV)}	Average forward current δ = 0.5, square wave	SMB	T _L = 140 °C	1	Α
		DO-15	T _L = 105 °C	-	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$			30	Α
T _{stg}	Storage temperature range			-65 to +175	°C
Tj	Operating junction temperature	+175	°C		

Table 2. Thermal resistance parameter

Symbol		Parameter				
	lunction to load		SMA	35		
R _{th(j-l)}	Junction to lead		SMB	25	°C/W	
	Junction to lead	unction to lead Lead length = 10 mm on infinite heatsink				

For more information, please refer to the following application note:

• AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	L (1)		V _R = V _{RRM}	-		5	μA
'R\'	Reverse leakage current	T _j = 125 °C	VR - VRRM	-	5	50	μΑ
		T _j = 25 °C		-		1.50	
V _F ⁽²⁾	V _F ⁽²⁾ Forward voltage drop		I _F = 1 A	-	1.0	1.25	V
				-	0.9	1.15	

- 1. Pulse test: $t_p = 5$ ms, $\delta < 2\%$
- 2. Pulse test: t_p = 380 μ s, δ < 2%

To evaluate the conduction losses, use the following equation:

$$P = 0.9 \times I_{F(AV)} + 0.250 \times I_{F}^{2}_{(RMS)}$$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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Table 4. Dynamic characteristics (T_j = 25 °C unless otherwise stated)

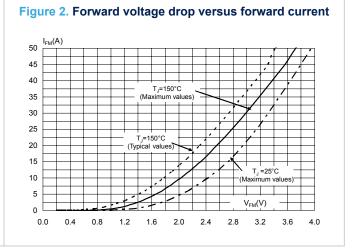
Symbol	Parameters	Test conditions	Min.	Тур.	Max.	Unit
+	Reverse recovery time	$I_F = 1 \text{ A}, dI_F/dt = -50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$	-		30	no
t _{rr}	Reverse recovery time	I_F = 1 A, dI_F/dt = -100 A/ μ s, V_R = 30 V	-	14	20	ns
I _{RM}	Reverse recovery current	I_F = 1 A, dI_F/dt = -200 A/ μ s, V_R = 320 V, T_j = 125 °C	-	2.5	3.5	Α
t _{fr}	Forward recovery time	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s, V}_{FR} = 1.1 \text{ x V}_{F(max.)}$	-		50	ns
V_{FP}	Forward recovery voltage	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	3.5		V

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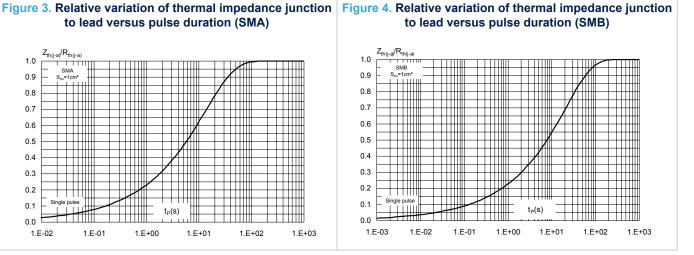


1.1 **Characteristics (curves)**

Figure 1. Average forward power dissipation versus average forward current 1.6 1.4 1.2 1.0 0.8 0.6 0.4 0.2 $I_{F(AV)}(A)$ δ=tp/T 0.0 0.0 1.0



to lead versus pulse duration (SMA) 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 $t_P(s)$ 0.0 1.E-01 1.E-02 1.E+02 1.E+03 1.E+00 1.E+01



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Figure 5. Relative variation of thermal impedance junction to lead versus pulse duration (DO-15)

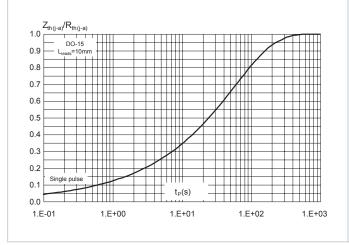


Figure 6. Reverse recovery charges versus dl_F/dt (typical values)

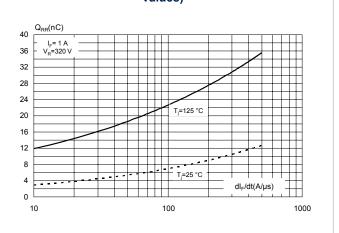


Figure 7. Junction capacitance versus reverse voltage applied (typical values)

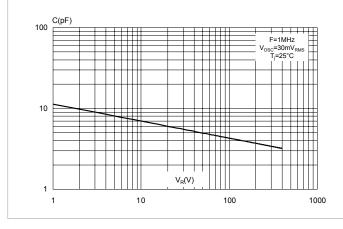


Figure 8. Reverse recovery time versus dl_F/dt (typical values)

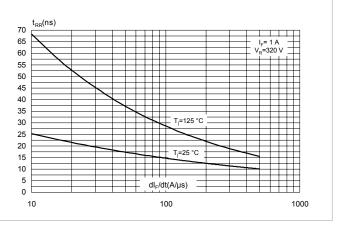


Figure 9. Peak reverse recovery current versus dl_F/dt (typical values)

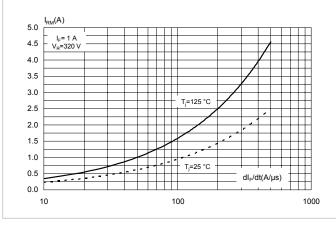
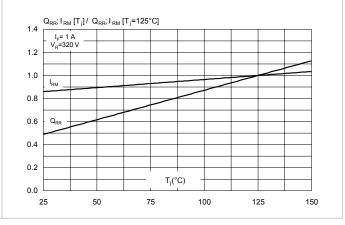


Figure 10. Relative variations of dynamic parameters versus junction temperature



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Figure 11. Transient peak forward voltage versus dl_F/dt (typical values)

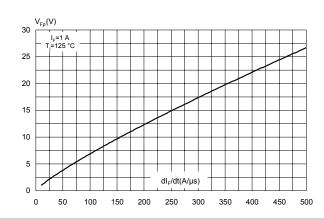


Figure 12. Forward recovery time versus dI_F/dt (typical values)

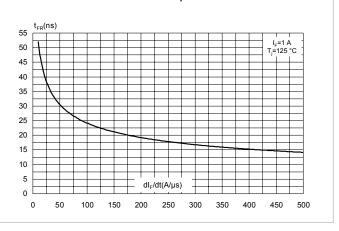


Figure 13. Thermal resistance junction to ambient versus copper surface under each lead (typical values)

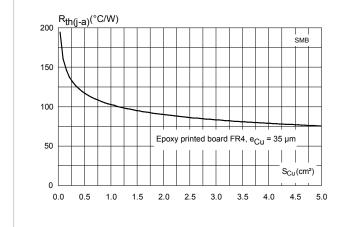


Figure 14. Thermal resistance junction to ambient versus copper surface under each lead (typical values)

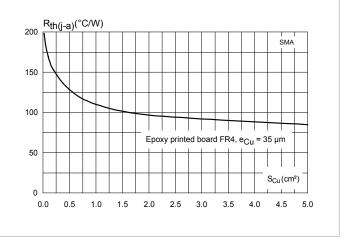
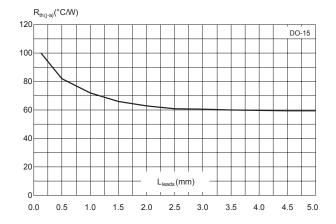


Figure 15. Thermal resistance junction to ambient versus lead length, DO-15



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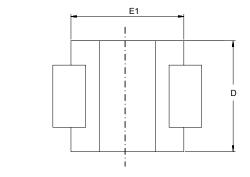
2 Package information

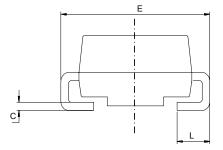
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

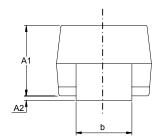
2.1 SMB package information

- Epoxy meets UL94, V0
- · Lead-free package

Figure 16. SMB package outline







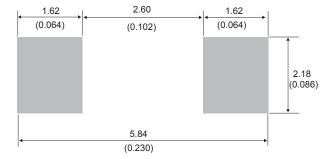
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Table 5. SMB package mechanical data

	Dimensions					
Ref.	Millin	neters	Inches (for re	eference only)		
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.074	0.097		
A2	0.05	0.20	0.001	0.008		
b	1.95	2.20	0.076	0.087		
С	0.15	0.40	0.005	0.016		
D	3.30	3.95	0.129	0.156		
E	5.10	5.60	0.200	0.221		
E1	4.05	4.60	0.159	0.182		
L	0.75	1.50	0.029	0.060		

Figure 17. SMB recommended footprint



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2.2 SMA package information

- Epoxy meets UL94, V0
- Cooling method : by conduction (C)

Figure 18. SMA package outline

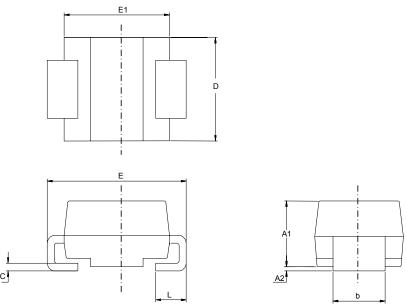


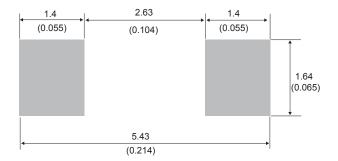
Table 6. SMA package mechanical data

	Dimensions					
Ref.	Millin	neters	Inches (for re	ference only)		
	Min.	Max.	Min.	Max.		
A1	1.90	2.45	0.074	0.097		
A2	0.05	0.20	0.001	0.008		
b	1.25	1.65	0.049	0.065		
С	0.15	0.40	0.005	0.016		
D	2.25	2.90	0.088	0.115		
E	4.80	5.35	0.188	0.211		
E1	3.95	4.60	0.155	0.182		
L	0.75	1.50	0.029	0.060		

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Figure 19. SMA recommended footprint in mm (inches)



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2.3 DO-15 package information

• Epoxy meets UL 94, V0

Figure 20. DO-15 package outline

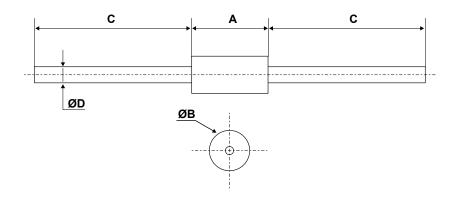


Table 7. DO-15 package mechanical data

	Dimensions					
Ref.		Millimeters			es (for reference	only)
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	6.05	-	6.75	0.238	-	0.266
В	2.95	-	3.53	0.116	-	0.139
С	26.00	-	31.00	1.024	-	1.220
D	0.71	-	0.88	0.028	-	0.0035

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3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH1R04A	HR4	SMA	0.068 g	5000	Tape and reel
STTH1R04U	BR4	SMB	0.107 g	2500	Tape and reel
STTH1R04QRL	STTH1R04Q	DO-15	0.400 g	6000	Tape and reel

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Revision history

Table 9. Document revision history

Date	Revision	Changes	
30-May-2008	1	First issue.	
12-Nov-2015	2	Updated Figure 3, Figure 4, Figure 5 and Figure 6. Minor text changes.	
13-Nov-2018	3	Removed DO-41 package information.	
15-Mar-2019	4	Updated Table 3. Static electrical characteristics.	



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